

Technical Data Sheet

Infrared MIDLED LED

HIR89-01C/1R

Features

- Low forward voltage.
- View angle 30° (Typ.)
- Pb free
- The product itself will remain within RoHS compliant version.
- Compatible with infrared and vapor phase reflow solder process
- Taping as Top view.



Descriptions

• HIR89-01C/1R is an infrared emitting diode with miniature MIDLED package. The device is spectrally matched with silicon photodiode and phototransistor.

Applications

• Infrared applied system

Device Selection Guide

LED Dont No	Chip	Long Color	
LED Part No.	Material	Lens Color	
HIR89-01C/1R	GaAlAs	Water clear	

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Prepared by: JAINE TSAI Device No: DIR-0000413 Prepared date: 12-10-2010 : 1

Release Date:2010-12-16 13:53:02.0

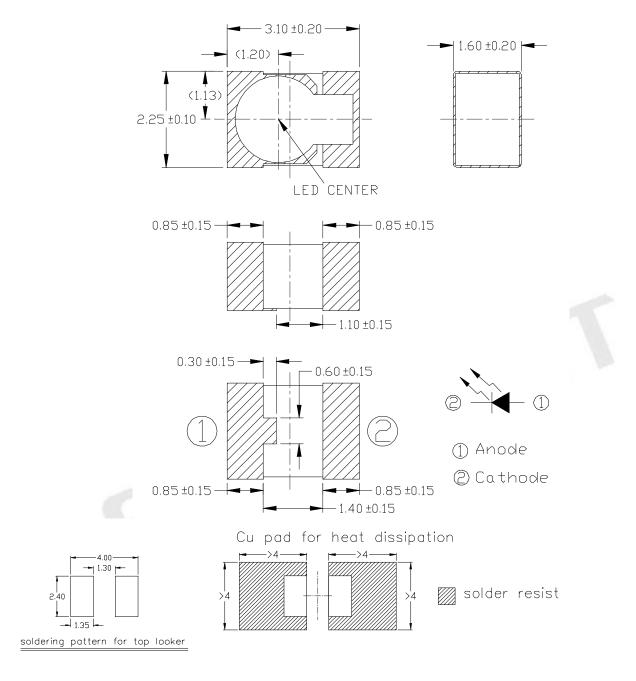
Expired Period: Forever

LifecyclePhase:正式發行

Revision



Package Dimensions



Notes: 1.All dimensions are in millimeters

2.Tolerances unless dimensions ±0.1mm

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Absolute Maximum Ratings (Ta=25)

Parameter	Symbol	Rating	Units
Continuous Forward Current	I_{F}	65	mA
Peak Forward Current *1	I_{FP}	200	mA
Reverse Voltage	V_R	5	V
Operating Temperature	T_{opr}	-40~ +85	
Storage Temperature	T_{stg}	-40 ~ +100	
Soldering Temperature *2	T_{sol}	260	
Power Dissipation at(or below)	P_{d}	100	mW
25 Free Air Temperature			

Notes: *1: I_{FP} Conditions--Pulse Width 500 μ s and Duty 5%.

Electro-Optical Characteristics (Ta=25)

Electro-Optical Characteristics (Ta=25)						
Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Radiant Intensity	$I_{\rm E}$	$I_F=70\text{mA}$, $tp=20\text{ms}$	25	1	125	mW/sr
Peak Wavelength	p	$I_F=100\text{mA}$	840	850	870	nm
Spectral Bandwidth		$I_F=100\text{mA}$	\\	30		nm
Forward Voltage	V _F	$I_F=20mA$	1-	1.40	1.70	V
		$I_F=70\text{mA}, \text{tp}=20\text{ms}$		1.55	1.90	V
Reverse Current	I_R	$V_R=5V$			10	μA
Rise time	tr	I _F =20mA		16		ns
Fall time	tf	$I_F=20mA$		30		ns
View Angle	2 1/2	$I_F=20\text{mA}$		30		deg

Rank

Condition: I_F=70mA

Unit: mW/sr

Bin Number	В	C	D
Min	25	40	63
Max	50	80	125

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^{*2:}Soldering time 5 seconds.



Typical Electro-Optical Characteristics Curves

Fig.1 Forward Current vs. **Ambient Temperature**

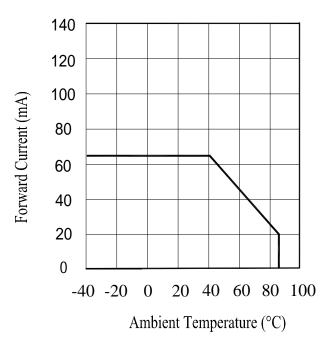
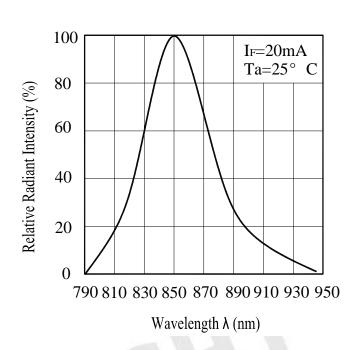
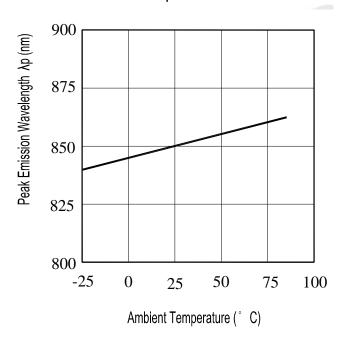


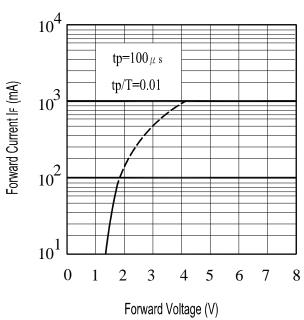
Fig.2 Spectral Distribution



Peak Emission Wavelength Fig.3 **Ambient Temperature**



Forward Current Fig.4 vs. Forward Voltage



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Typical Electro-Optical Characteristics Curves

Fig.5 Relative Intensity vs.
Forward Current

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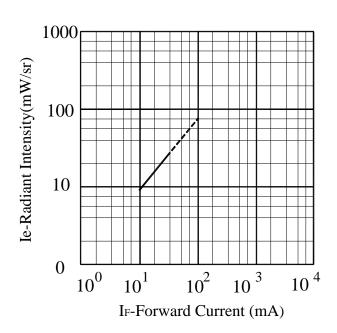
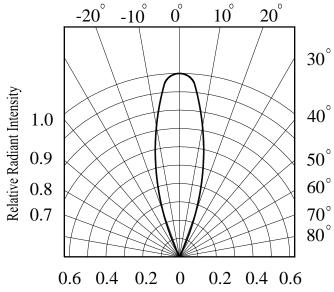


Fig.6 Relative Radiant Intensity vs.

Angular Displacement



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Precautions For Use

1. Over-current-proof

Customer must apply resistors for protection, otherwise slight voltage shift will cause big current change (Burn out will happen).

2. Storage

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- 2.1 Do not open moisture proof bag before devices are ready to use.
- 2.2 Shelf life in sealed bag from the bag seal date:

18 months at 10° C \sim 30 $^{\circ}$ C and < 90 $^{\circ}$ RH.

- 2.3 After opening the package, the devices must be stored at $10^{\circ}\text{C}\sim30^{\circ}\text{C}$ and $\leq 60\%\text{RH}$, and used within 72 hours(floor life).
- 2.4 If the moisture absorbent material(desiccant material) has faded or unopened bag has exceeded the shelf life or devices(out of bag) have exceeded the floor life, baking treatment is required.
- 2.5 If baking is required, refer to IPC/JEDEC J-STD-033 for bake procedure or recommend the following conditions :

192 hours at $40^{\circ}\text{C} + 5/-0^{\circ}\text{C}$ and < 5 % RH (reeled/tubed/loose units) or

96 hours at $60^{\circ}\text{C} \pm 5^{\circ}\text{C}$ and < 5 % RH (reeled/tubed/loose units) or

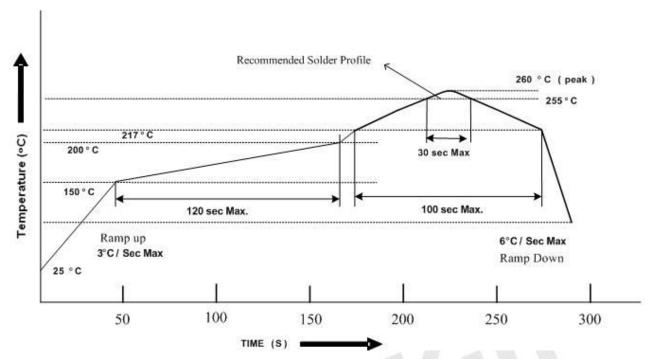
24 hours at $125^{\circ}\text{C} \pm 5^{\circ}\text{C}$, not suitable for reel or tubes.

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3. Soldering Condition

3.1 Pb-free solder temperature profile



- 3.2 Reflow soldering should not be done more than two times.
- 3.3 When soldering, do not put stress on the LEDs during heating.
- 3.4 After soldering, do not warp the circuit board.

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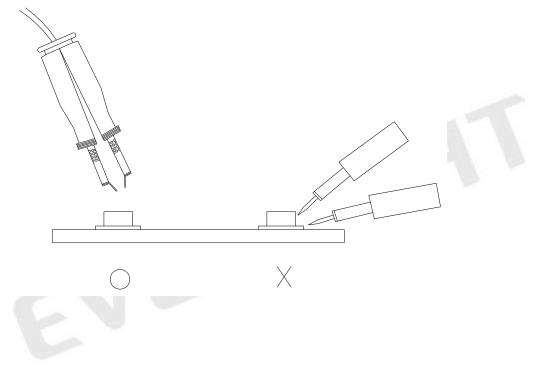


4. Soldering Iron

Each terminal is to go to the tip of soldering iron temperature less than 350 for 3 seconds within once in less than the soldering iron capacity 25W. Leave two seconds and more intervals, and do soldering of each terminal. Be careful because the damage of the product is often started at the time of the hand solder.

5.Repairing

Repair should not be done after the LEDs have been soldered. When repairing is unavoidable, a double-head soldering iron should be used (as below figure). It should be confirmed beforehand whether the characteristics of the LEDs will or will not be damaged by repairing.



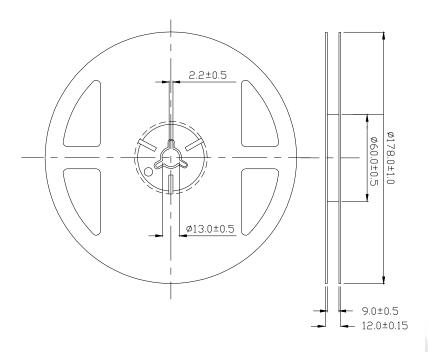
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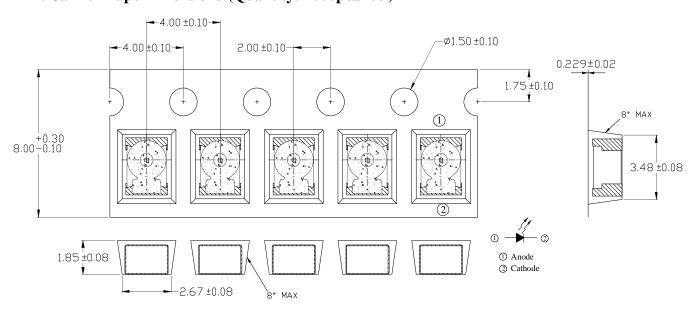


Package Dimensions



Note: The tolerances unless mentioned is ± 0.1 mm, Unit = mm

2. Carrier Tape Dimensions:(Quantity: 2000pcs/reel)



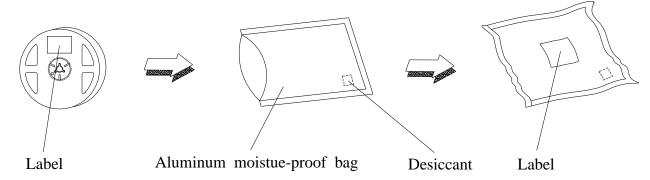
Note: The tolerances unless mentioned is ± 0.1 mm, Unit = mm

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Packing Procedure

HIR89-01C/1R



Label Form Specification



CPN: Customer's Production Number

P/N: Production Number QTY: Packing Quantity

CAT: Ranks

HUE: Peak Wavelength

REF: Reference

LOT No: Lot Number

MADE IN TAIWAN: Production Place

Notes

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- 1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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